



GAM2501 thru GAM2512

High Voltage Press Fit Diodes For Automotive
Voltage Range 100 to 1200Volts Current 25 Amps

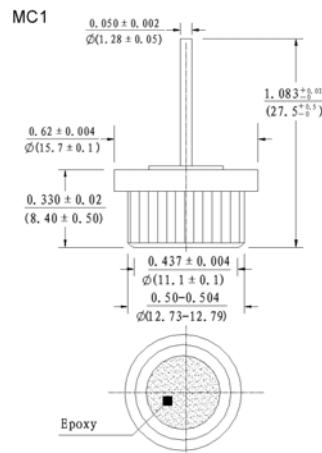
Technical Specification:

Features:

- ◆ Low leakage
- ◆ Low forward voltage drop
- ◆ High current capability
- ◆ High forward surge current capability

Mechanical Data:

- ◆ Technology: Gpp chip or cell, Cell with vacuum soldered
- ◆ Case: Copper case
- ◆ Polarity: As marked of case bottom
- ◆ Lead: Plated lead, solderable per MIL-STD-202E method 208C
- ◆ Mounting: Press Fit
- ◆ Weight: 0.30 ounces, 8.5 grams



Dimensions in inches and (millimeters)

■Maximum Ratings and Electrical Characteristics

- ◆ Rating at 25°C ambient temperature unless otherwise specified.
- ◆ Single phase, half wave, 60Hz, resistive or inductive load.
- ◆ For capacitive load derate current by 20%.

Parameters	Symbols	GAM2501	GAM2502	GAM2504	GAM2506	GAM2508	GAM2510	GAM2512	Units
Maximum repetitive peak reverse voltage	V _{RRM}	100	200	400	600	800	1000	1200	Volts
Maximum RMS voltage	V _{RMS}	70	140	280	420	560	700	840	Volts
Maximum DC blocking voltage	V _{DC}	100	200	400	600	800	1000	1200	Volts
Maximum Average rectified forward current at T _C =105°C	I _(AV)					25			Amps
Peak forward surge current 8.3mS single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}					300			Amps
Rating for fusing (t<8.3mS)	I _f					374			A ² S
Maximum instantaneous forward voltage drop at 35A	V _F				1.0				Volts
Maximum DC reverse current T _A =25°C at rated DC blocking voltage T _C =150°C	I _R				5.0				uA mA
Typical thermal resistance	R _{θJL}				0.5				°C/W
Operating and storage temperature range	T _J , T _{STG}				-65 to +175				°C

Notes: 1. Enough heatsink must be considered in application.

■ Ratings and Characteristic Curves

FIG.1—TYPICAL FORWARD CURRENT DERATING CURVE

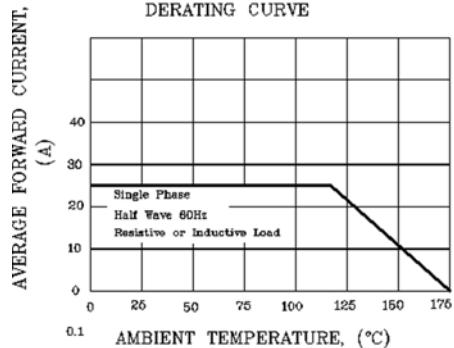


FIG.2—MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

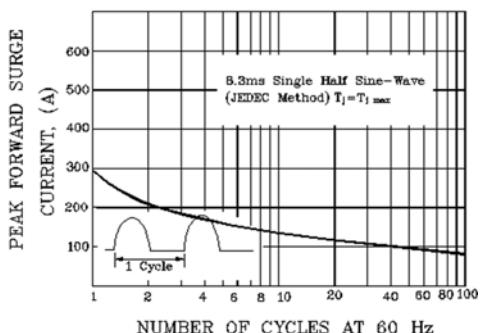


FIG.3—TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

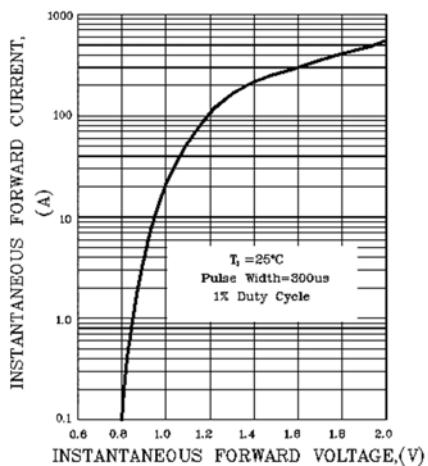


FIG.4—FORWARD POWER DISSIPATION

